

VOLTAGE DETECTOR

AZ70XX

General Description

The AZ70XX series ICs are under voltage detectors with a built in voltage threshold and low power consumption. The AZ70XX are specifically designed to accurately monitor power supplies.

The AZ70XX use a precision on-chip voltage reference and a comparator to measure the input operating voltage. These ICs can accurately reset the system after detecting voltage at the time of switching power on and instantaneous power off in various CPU systems and other logic systems. The detect voltage thresholds are 2.3V/2.5V/2.7V/2.9V/3.1V/3.3V/4.2V/4.5V for AZ7023/25/27/29/31/33/42/45 respectively. Built in hysteresis helps to prevent erratic operation in the presence of noise.

The AZ70XX series are available in 2 standard packages: TO-92 (bulk or ammo packing) and SOT-89.

Features

- Low Current Consumption:
 $I_{CCL}=300\mu A$ Typical
 $I_{CCH}=30\mu A$ Typical
- Low Minimum Operating Voltage for Output Resetting: 0.8V Typical
- Built in Hysteresis Voltage: 50mV Typical
- Open Collector Output
- Extended Temperature Range: -40 to 85°C

Applications

- Low Battery Voltage Detector
- Power Fail Indicator
- Processor Reset Generator
- Battery Backup Control
- Home Electric Appliances



Figure 1. Package Types of AZ70XX

VOLTAGE DETECTOR

AZ70XX

Pin Configuration

Z Package
(TO-92(Bulk Packing))



Z Package
(TO-92(Ammo Packing))



R Package
(SOT-89)



Figure 2. Pin Configuration of AZ70XX (Top View)

Functional Block Diagram



Figure 3. Functional Block Diagram of AZ70XX

**VOLTAGE DETECTOR****AZ70XX****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
Supply Voltage	V_{CC}	-0.3 to 20	V
Power Dissipation (Package Limitations, $T_A=25^{\circ}\text{C}$)	P_D	TO-92 Package: 400	mW
		SOT-89 Package: 500	
Operating Junction Temperature	T_J	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	-65 to 150	$^{\circ}\text{C}$

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
Supply Voltage	V_{CC}		18	V
Operating Temperature Range	T_A	-40	85	$^{\circ}\text{C}$



VOLTAGE DETECTOR

AZ70XX

Electrical Characteristics

T_A=25°C, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit	
Detect Voltage	V _{DET}	R _L =200Ω (Note 2) V _{OL} ≤ 0.4V	AZ7023R/Z	2.15	2.3	2.45	V
			AZ7025R/Z	2.35	2.5	2.65	
			AZ7027R/Z	2.55	2.7	2.85	
			AZ7029R/Z	2.75	2.9	3.05	
			AZ7031R/Z	2.95	3.1	3.25	
			AZ7033R/Z	3.15	3.3	3.45	
			AZ7042R/Z	4.05	4.2	4.35	
			AZ7045R/Z	4.35	4.5	4.65	
Low-level Output Voltage	V _{OL}	V _{CC} =V _{DET} (min)-0.05V R _L =200Ω (Note 2)			0.4	V	
Output Leakage Current	I _{OH}	V _{CC} =18V			0.1	μA	
Hysteresis Voltage	V _{HYS}	R _L =200Ω (Note 2)	30	50	100	mV	
Detect Voltage Temperature Coefficient	$\frac{\Delta V_{DET}}{V_{DET}} \times \Delta T$	R _L =200Ω (Note 2)		±0.01		% /°C	
Circuit Current at On Time	I _{CCL}	V _{CC} =V _{DET} (min)-0.05V		300	500	μA	
Circuit Current at Off Time	I _{CCH}	V _{CC} =5.25V		30	50	μA	
Minimum Operating Voltage	V _{OPR}	R _L =200Ω (Note 2) V _{OL} ≤ 0.4V		0.8		V	
“L” Transmission Delay Time	tpHL	V _{CC} changed from 5.25V to V _{DET} (min)-0.05V, R _L =1.0KΩ, C _L =100p (Note 3)		10		μs	
“H” Transmission Delay Time	tpLH	V _{CC} changed from V _{DET} (min)-0.05V to 5.25V, R _L =1.0KΩ, C _L =100p (Note 3)		15		μs	
Output Current at On Time	I _{OL I}	V _{CC} =V _{DET} (min)-0.05V T _A =25°C (Note 4)	20			mA	
	I _{OL II}	V _{CC} =V _{DET} (min)-0.05V T _A =-40 to 85 °C (Note 4)	16				
Thermal Resistance (Junction to Case)	θ _{JC}	TO-92		72		°C/W	
		SOT-89		74			

Note 2: See test circuit 1 and Figure 12.

Note 3: See test circuit 2 and Figure 12.

Note 4: See test circuit 3. Adjusting the regulative power source until the reading value of voltage meter V is 0.4V, the reading value of current meter A is defined as "Output Current at On Time".

VOLTAGE DETECTOR

AZ70XX

Electrical Characteristics (Continued)



Figure 4. Test Circuit 1



Figure 5. Test Circuit 2



Figure 6. Test Circuit 3



VOLTAGE DETECTOR

AZ70XX

Typical Performance Characteristics



Figure 7. Detect Voltage vs. Temperature



Figure 8. Minimum Operating Voltage vs. Temperature



Figure 9. Output Current at On Time vs. Temperature

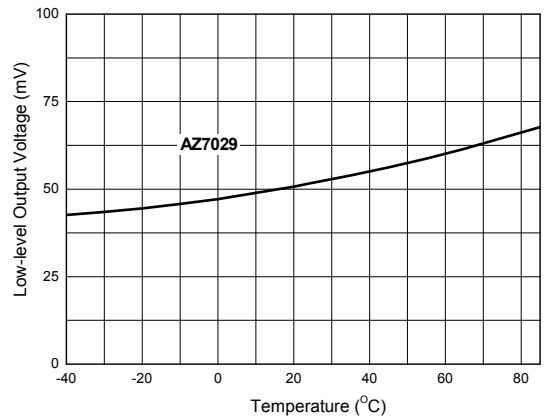


Figure 10. Low-level Output Voltage vs. Temperature

Typical Performance Characteristics (Continued)



Figure 11. Output Voltage Dynamic Response when V_{CC} Increases and Decreases

Operating Diagram



Figure 12. AZ70XX Timing Waveform (Note 5)

Note 5: Detect voltage: V_{DET-}

Hysteresis voltage (V_{HYS}): $V_{DET+} - V_{DET-}$

Release voltage: V_{DET+}

Minimum operating voltage: V_{OPR}

VOLTAGE DETECTOR

AZ70XX

Operating Diagram (Continued)

Figure 12 is a typical timing waveform for AZ70XX. In normal steady-state operation when $V_{CC} > V_{DET-}$, the output will be in a logic high state and V_{OUT} is dependent upon the voltage that the pull-up resistor connected to.

Here is some explanations for AZ70XX's operation.

1. When the input voltage V_{CC} falls below V_{DET-} , the output will pull down to logic low after a delay time of t_{pHL} . In general, at rated output current and V_{CC} , V_{OUT} can be pulled down to a voltage as low as within 0.4V from GND. (See the Electrical Characteristics section). The voltage level V_{DET-} means the detect voltage.

2. The output, V_{OUT} , will stay valid until V_{CC} falls below the minimum operating voltage, V_{OPR} (0.8V

typical). Below minimum operating voltage, the output is undefined.

3. During power-up, V_{OUT} will remain undefined until V_{CC} rises above V_{OPR} , at which time the output will become valid. V_{OUT} will be in its active low state while $V_{OPR} < V_{CC} < V_{DET+}$ ($V_{DET+} = V_{DET-} + V_{HYS}$). V_{DET+} is the release voltage. V_{HYS} means the hysteresis voltage and is the difference voltage between the V_{DET+} and V_{DET-} .

4. When V_{CC} rises above V_{DET+} , the output will be in its inactive state. After a delay time of t_{pLH} , V_{OUT} will be in its logic high state .

Typical Applications



Figure 13. Low Voltage Indicator

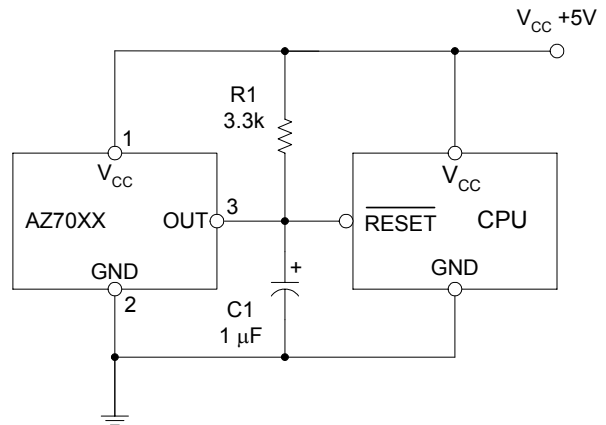


Figure 14. CPU Resetting Circuit



VOLTAGE DETECTOR

AZ70XX

Mechanical Dimensions

TO-92(Bulk Packing)

Unit: mm(inch)





VOLTAGE DETECTOR

AZ70XX

Mechanical Dimensions (Continued)

TO-92(Ammo Packing)

Unit: mm(inch)





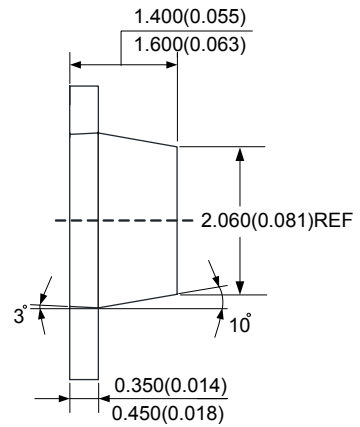
VOLTAGE DETECTOR

AZ70XX

Mechanical Dimensions (Continued)

SOT-89

Unit: mm(inch)





BCD Semiconductor Manufacturing Limited

<http://www.bcdsemi.com>

IMPORTANT NOTICE

BCD Semiconductor Manufacturing Limited reserves the right to make changes without further notice to any products or specifications herein. BCD Semiconductor Manufacturing Limited does not assume any responsibility for use of any its products for any particular purpose, nor does BCD Semiconductor Manufacturing Limited assume any liability arising out of the application or use of any its products or circuits. BCD Semiconductor Manufacturing Limited does not convey any license under its patent rights or other rights nor the rights of others.

MAIN SITE

- Headquarters

BCD Semiconductor Manufacturing Limited

No. 1600, Zi Xing Road, Shanghai Zizhu Science-based Industrial Park, 200241, China
Tel: +86-21-24162266, Fax: +86-21-24162277

- Wafer Fab

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd.

800 Yi Shan Road, Shanghai 200233, China
Tel: +86-21-6485 1491, Fax: +86-21-5450 0008

REGIONAL SALES OFFICE

Shenzhen Office

Shanghai SIM-BCD Semiconductor Manufacturing Co., Ltd., Shenzhen Office

Unit A Room 1203, Skyworth Bldg., Gaoxin Ave. 1.S., Nanshan District, Shenzhen, China
Tel: +86-755-8826 7951
Fax: +86-755-8826 7865

Taiwan Office

BCD Semiconductor (Taiwan) Company Limited

4F, 298-1, Rui Guang Road, Nei-Hu District, Taipei, Taiwan
Tel: +886-2-2656 2808
Fax: +886-2-2656 2806

USA Office

BCD Semiconductor Corp.

30920 Huntwood Ave. Hayward, CA 94544, USA
Tel : +1-510-324-2988
Fax: +1-510-324-2788

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9